

isc Silicon PNP Transistor

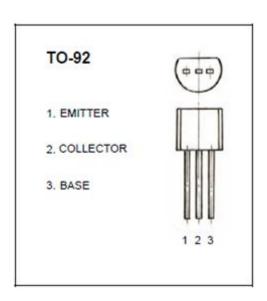
2SA1283

DESCRIPTION

- High Voltage and High Current Vceo=-60V(Min.)
- Excellent hFE Linearity
- Low Noise
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

- Audio frequency general purpose amplifier Applications
- Driver stage amplifier applications.



ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
Vсво	Collector-Base Voltage	-60	V
V _{CEO}	Collector-Emitter Voltage	-60	V
V _{EBO}	Emitter-Base Voltage	-6	V
Ic	Collector Curren	-1	А
Pc	Collector Power Dissipation @T _C =25 °C	900	mW
TJ	Junction Temperature	150	°C
Tstg	Storage Temperature Range	-55~150	°C



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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = -500mA ; I _B = -25mA			-0.3	V
I _{CBO}	Emitter Cutoff Current	V _{CB} = -50V; I _E = 0			-0.2	μ A
I _{EBO}	Collector Cutoff Current	V _{EB} = -4V; I _C = 0			-0.2	μ A
h _{FE}	DC Current Gain	I _C = -100mA ; V _{CE} = -4V	55		300	

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С	D	E
55-110	90-180	150-300



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